



DMTH10H025LPSQ

100V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	Ι _D T _C = +25°C	
(00) (23mΩ @ V _{GS} = 10V	45A	
100V	$30m\Omega @ V_{GS} = 6V$	38A	

Description

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Synchronous Rectifier
- **DC-DC Converters**
- Primary Side Switching

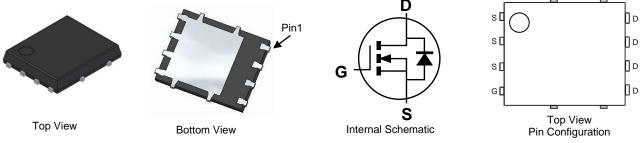
Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable And Robust End Application
- Low R_{DS(ON)} Minimizes On-State Losses
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 03
- Weight: 0.097 grams (Approximate)





Ordering Information (Note 5)

Part Number		Case	Packaging	
DMTH10H025LPSQ-13		PowerDI5060-8	2,500 / Tape & Reel	
Notes:	1. EU Directive 2002/95/EC (RoHS), 2011/6	5/EU (RoHS 2) & 2015/863/EU (RoHS 3) complia	nt. All applicable RoHS exemptions applied.	

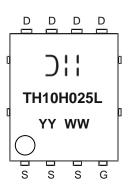
EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All app able RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



D | | = Manufacturer's Marking TH10H025L = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 19 = 2019) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	100	V	
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current, $V_{GS} = 10V$ (Note 6) $T_A = +25^{\circ}C$ $T_A = +100^{\circ}C$		Ι _D	9.3 6.6	А
Continuous Drain Current, $V_{GS} = 10V$ (Note 7) $T_C = +25^{\circ}C$ $T_C = +100^{\circ}C$		ID	45 32	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	90	А	
Maximum Continuous Body Diode Forward Current (Note 7)	ls	45	A	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)	I _{SM}	90	А	
Avalanche Current (Note 8), L=0.1mH	I _{AS}	15.8	А	
Avalanche Energy (Note 8), L=0.1mH	E _{AS}	12.5	mJ	
Avalanche Current (Note 8), L=3mH	I _{AS}	8	А	
Avalanche Energy (Note 8), L=3mH	E _{AS}	96	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$	PD	3.2	W
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	46	°C/W	
Total Power Dissipation (Note 7)	$T_{\rm C} = +25^{\circ}{\rm C}$	PD	79	W
Thermal Resistance, Junction to Case (Note 7)	R _{θJC}	1.9	°C/W	
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +175	С°	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

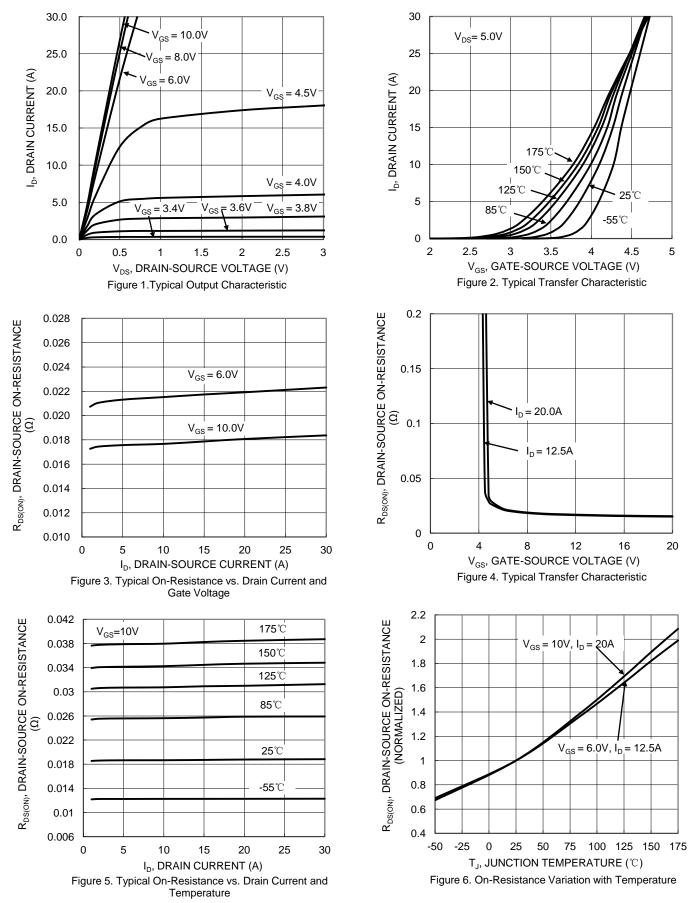
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)			, ,				
Drain-Source Breakdown Voltage	BV _{DSS}	100	_	—	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	1	_	3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance		—	18	23	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	21	30	11122	V _{GS} = 6V, I _D = 12.5A	
Diode Forward Voltage	V _{SD}	_	0.9	1.3	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}	—	1477	_		$V_{DS} = 50V, V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss	_	263	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	20	_			
Gate Resistance	Rg	_	1.3	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	21	_			
Gate-Source Charge	Q _{gs}	_	5.7	—	nC	$V_{DD} = 50V, I_D = 20A,$	
Gate-Drain Charge	Q _{gd}	_	3.8	—		$V_{GS} = 10V$	
Turn-On Delay Time	t _{D(ON)}	_	6.3	—			
Turn-On Rise Time	t _R	_	9.4	_		$V_{DD} = 50V, V_{GS} = 10V,$ $I_D = 20A, R_g = 6\Omega$	
Turn-Off Delay Time	t _{D(OFF)}	_	16.7	—	ns		
Turn-Off Fall Time	t _F	_	8.2	—	1		
Reverse Recovery Time	t _{RR}	_	38.7	—	ns		
Reverse Recovery Charge	Q _{RR}	_	53.7	_	nC	$I_{\rm F} = 20$ A, di/dt = 100A/µs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).
Short duration pulse test used to minimize self-heating effect. Notes:

9. Guaranteed by design. Not subject to product testing.

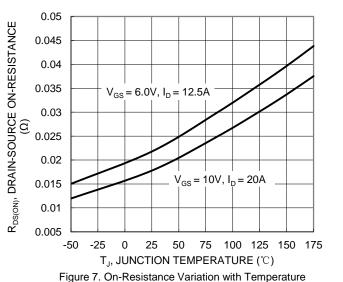


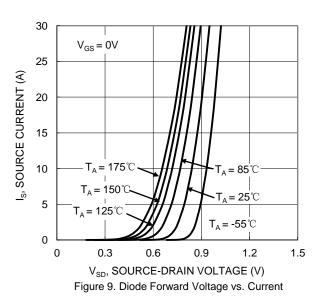
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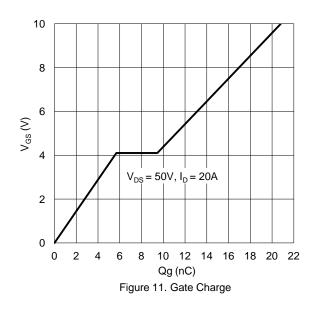


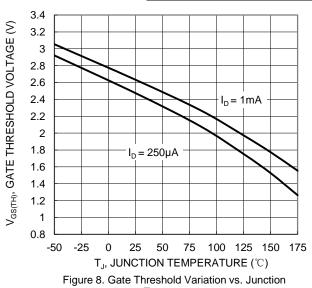




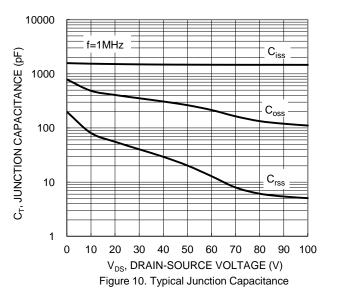


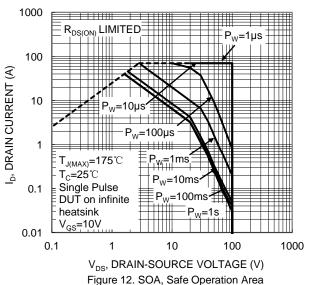






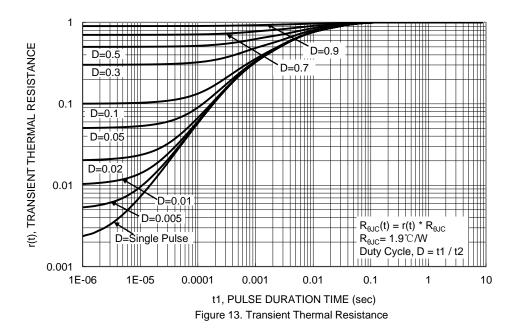








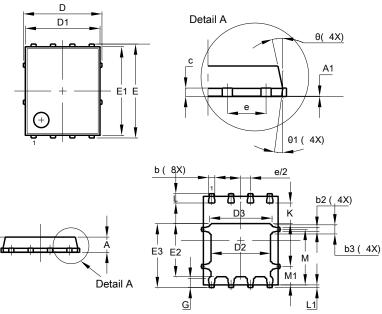






Package Outline Dimensions

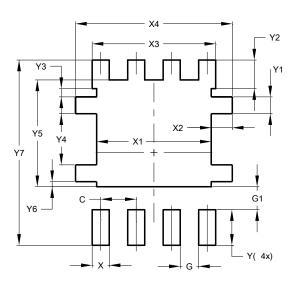
Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D		5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
E	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е		1.27 BSC	;		
G	0.51	0.71	0.61		
K	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

PowerDI5060-8

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